

LME49743 Quad High Performance, High Fidelity Audio Operational Amplifier

Check for Samples: LME49743

FEATURES

- Easily Drives 600Ω Loads
- Optimized for Superior Audio Signal Fidelity
- Output Short Circuit Protection
- 98dB (Typ) PSRR and 106dB (Typ) CMRR
- TSSOP Package

APPLICATIONS

- Audio Amplifiers and Preamplifiers
- Professional Audio
- Equalization and Crossover Networks
- Line Drivers and Receivers
- Active Filters

DESCRIPTION

The LME49743 is a low distortion, low noise, high slew rate operational amplifier optimized and fully specified for high performance, high fidelity applications. The LME49743 audio operational amplifier delivers superior audio signal amplification for outstanding audio performance. The LME49743 combines low voltage noise density (3.5nV/√Hz) and THD+N (0.0001%) to easily satisfy demanding audio applications. To ensure that the most challenging loads are driven without compromise, the LME49743 has a slew rate of ±12V/µs and an output current capability of ±21mA.

The LME49743's outstanding CMRR(106dB), PSRR(98dB), and V_{OS} (±0.15mV) give the amplifier excellent operational amplifier DC performance.

The LME49743 has a wide supply range of ±4.0V to ±17V. Over this supply range the LME49743's input circuitry maintains excellent common-mode, power supply rejection, and low input bias current. The LME49743 is unity gain stable.

The LME49743 is available in 14-lead TSSOP.

Table 1. Key Specifications

		VALUE	UNIT
Power Supply Voltage Range		±4.0V to ±17	V
THD+N ($A_V = 1$, $V_{OUT} = 3V_{RMS}$,	$R_L = 2k\Omega$	0.0001	% (typ)
$f_{IN} = 1kHz$	$R_L = 600\Omega$	0.0001	% (typ)
Input Noise Density		3.5	nV/√ Hz (typ)
Slew Rate		±12	V/µs (typ)
Gain Bandwidth Product		30	MHz (typ)
Open Loop Gain (R _L = 600Ω)		110	dB (typ)
Input Bias Current		190	nA (typ)
Input Offset Voltage		±0.15	mV (typ)

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Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



Connection Diagram

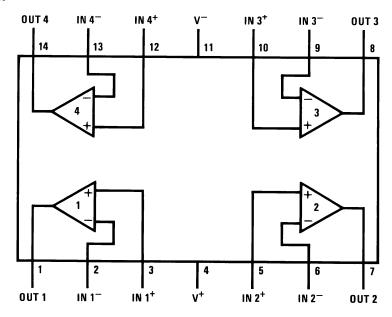


Figure 1. TSSOP Package See Package Number PW0014A



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings (1)(2)(3)

$(V_S = V^+ - V^-)$	36V
	−65°C to 150°C
	(V-) - 0.7V to (V+) + 0.7V
	Continuous
	Internally Limited
	750V
	175V
	150°C
θ _{JA} (MT)	140°C/W
$T_{MIN} \le T_A \le T_{MAX}$	-40°C ≤ T _A ≤ 85°C
	±4.0V ≤ V _S ≤ ± 17V
	θ _{JA} (MT)

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.
- (2) Operating Ratings indicate conditions for which the device is functional, but do not specify specific performance limits. For specifications and test conditions, see the Electrical Characteristics. The specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (3) If Military/Aerospace specifications are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.
- (4) Amplifier output connected to GND, any number of amplifiers within a package.
- (5) Human body model, 100pF discharged through a 1.5kΩ resistor.
- (6) Machine Model ESD test is covered by specification EIAJ IC-121-1981. A 200pF cap is charged to the specified voltage and then discharged directly into the IC with no external series resistor (resistance of discharge path must be under 50Ω).



Electrical Characteristics

The following specifications apply for $V_S = \pm 15V$, $R_L = 2k\Omega$, $f_{IN} = 1$ kHz, and $T_A = 25C$, unless otherwise specified. (1)(2)

			LME	49743	Unito
	Parameter	Test Conditions	Typ ⁽³⁾	Limit (4)(5)	Units (Limits)
THD+N	Total Harmonic Distortion + Noise	$A_V = 1, V_{OUT} = 3V_{RMS}$ $R_L = 2k\Omega$ $R_L = 600\Omega$	0.0001 0.0001	0.0002	% (max)
IMD	Intermodulation Distortion	$A_V = 1$, $V_{OUT} = 3V_{RMS}$ Two-tone, 60Hz & 7kHz 4:1	0.0005		% (max)
GBWP	Gain Bandwidth Product		30	25	MHz (min)
SR	Slew Rate		12	9.5	V/µs (min)
FPBW	Full Power Bandwidth	V _{OUT} = 1V _{P-P} , -3dB referenced to output magnitude at f = 1kHz	10		MHz
t _s	Settling time	A _V = 1, 10V step, C _L = 100pF 0.1% error range	1.2		μs
	Equivalent Input Noise Voltage	f _{BW} = 20Hz to 20kHz	0.48	0.65	μV_{RMS}
e _n	Equivalent Input Noise Density	f = 1kHz f = 10Hz	3.5 6.4	4.5	nV / √ Hz (max) nV / √ Hz
i _n	Current Noise Density	f = 1kHz f = 10Hz	1.6 3.1		pA / √ Hz pA / √ Hz
Vos	Offset Voltage		±0.15	±1.0	mV (max)
ΔV _{OS} /ΔTemp	Average Input Offset Voltage Drift vs Temperature	40°C ≤ T _A ≤ 85°C	0.05		μV/°C
PSRR	Average Input Offset Voltage Shift vs Power Supply Voltage	$\Delta V_{S} = 20V^{(6)}$	98	94	dB (min)
ISO _{CH-CH}	Channel-to-Channel Isolation	$\begin{aligned} f_{\text{IN}} &= 1 \text{kHz} \\ f_{\text{IN}} &= 20 \text{kHz} \end{aligned}$	118 112		dB dB
l _B	Input Bias Current	$V_{CM} = 0V$	190	250	nA (max)
ΔI _{OS} /ΔTemp	Input Bias Current Drift vs Temperature	-40°C ≤ T _A ≤ 85°C	0.05		nA/°C
los	Input Offset Current	$V_{CM} = 0V$	7	40	nA (max)
V _{IN-CM}	Common-Mode Input Voltage Range		±13.2	(V+)-2.0 (V-)+2.0	V (min) V (min)
CMRR	Common-Mode Rejection	-10V <v<sub>CM<10V</v<sub>	106	98	dB (min)
7	Differential Input Impedance		30		kΩ
Z _{IN}	Common Mode Input Impedance	-10V <v<sub>CM<10V</v<sub>	1000		ΜΩ
		$-10V < V_{OUT} < 10V, R_L = 600\Omega$	110		dB (min)
A _{VOL}	Open Loop Voltage Gain	$-10V < V_{OUT} < 10V, R_L = 2k\Omega$	110		dB (min)
		$-10V < V_{OUT} < 10V, R_L = 10k\Omega$	110	100	dB (min)
-		$R_L = 600\Omega$	±12.4	±12.0	V (min)
V _{OUTMAX}	Maximum Output Voltage Swing	$R_L = 2k\Omega$	±13.0		V (min)
		$R_L = 10k\Omega$	±13.0		V (min)
I _{оит}	Output Current	$R_L = 600\Omega, V_S = \pm 17V$	±21	±20	mA (min)
I _{OUT-CC}	Short Circuit Current		+30 -38		mA mA

⁽¹⁾ Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.

Product Folder Links: LME49743

⁽²⁾ Operating Ratings indicate conditions for which the device is functional, but do not specific performance limits. For specifications and test conditions, see the Electrical Characteristics. The specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

⁽³⁾ Typical specifications are specified at +25°C and represent the most likely parametric norm.

⁽⁴⁾ Tested limits are ensured to Texas Instrument's AOQL (Average Outgoing Quality Level).

⁽⁵⁾ Datasheet min/max specification limits are specified by design, test, or statistical analysis.

⁽⁶⁾ PSRR is measured as follows: V_{OS} is measured at two supply voltages, ±5V and ±15V. PSRR = |20log(ΔV_{OS}/ΔV_S)|.



Electrical Characteristics (continued)

The following specifications apply for $V_S = \pm 15 V$, $R_L = 2 k \Omega$, $f_{IN} = 1 k Hz$, and $T_A = 25 C$, unless otherwise specified. (1)(2)

			LME	49743	Units	
Parameter		Test Conditions	Typ ⁽³⁾	Limit (4)(5)	(Limits)	
R _{OUT}	Output Impedance	f _{IN} = 10kHz Closed-Loop Open-Loop	0.01 13		Ω	
C _{LOAD}	Capacitive Load Drive Overshoot	100pF	16		%	
I _S	Total Quiescent Current	I _{OUT} = 0mA	10	14	mA (max)	



Typical Performance Characteristics

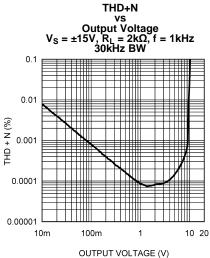
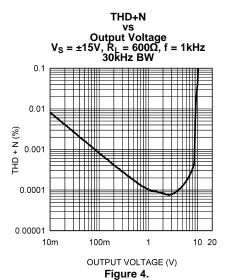
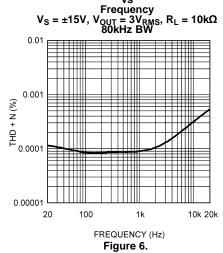


Figure 2.



THD+N vs Frequency



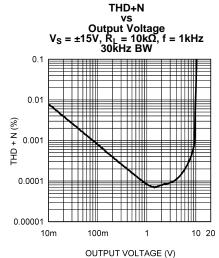


Figure 3.



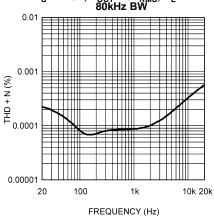
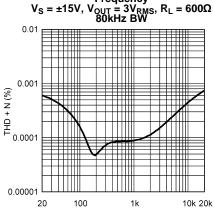


Figure 5.

THD+N vs Frequency ⊵15V, V_{OUT} = 3V_{RMS}, R_L = 600Ω 80kHz BW



FREQUENCY (Hz)
Figure 7.



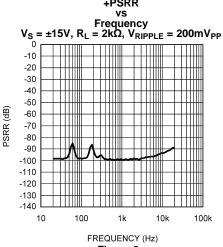


Figure 8.

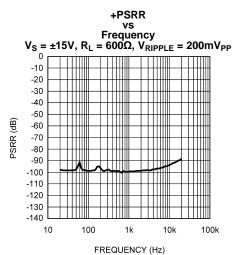


Figure 10.

-PSRR

Frequency $V_S = \pm 15V$, $R_L = 10k\Omega$, $V_{RIPPLE} = 200mV_{PP}$ -10 -20 -30 -40 -50 -60 -70 -80 -90 -100 -110 -120 -130 -140 10 100 1k 100k

FREQUENCY (Hz) Figure 12.

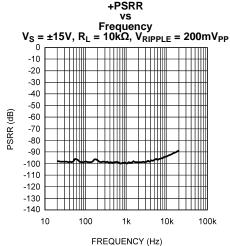


Figure 9.

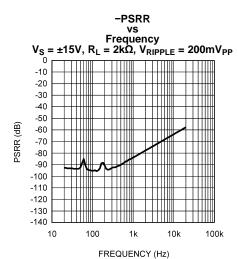


Figure 11.

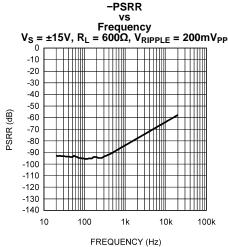
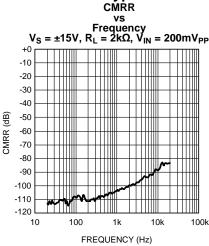


Figure 13.







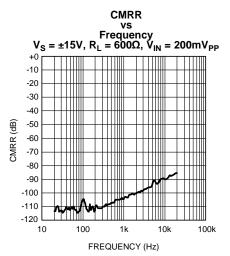
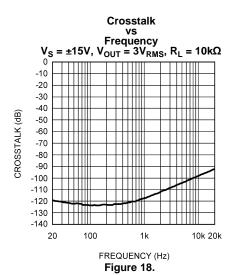


Figure 16.



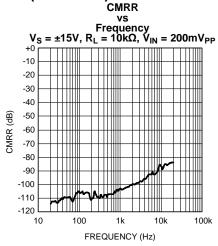


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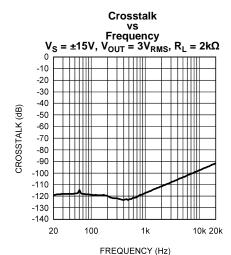


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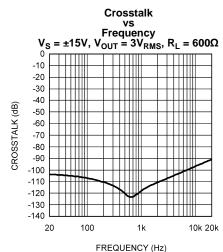


Figure 19.



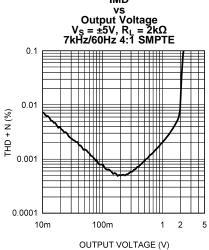
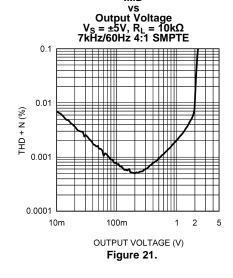


Figure 20.



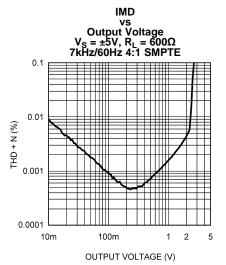


Figure 22.

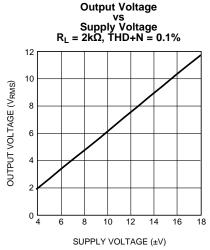


Figure 23.

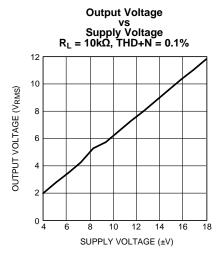


Figure 24.

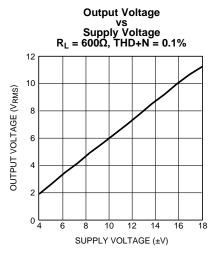
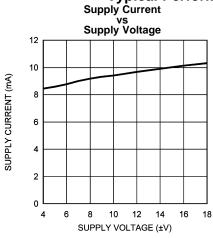
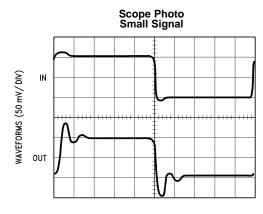


Figure 25.

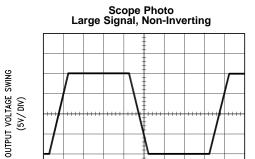




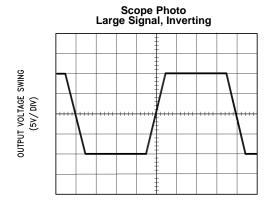




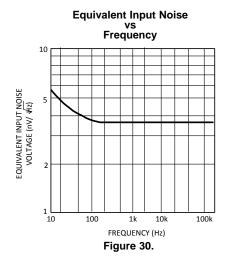
TIME (0.1 μ s / DIV) **Figure 27.**



TIME (1 μ s / DIV) **Figure 28.**



TIME (1 μ s / DIV) **Figure 29.**



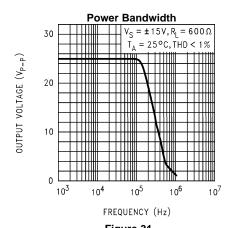
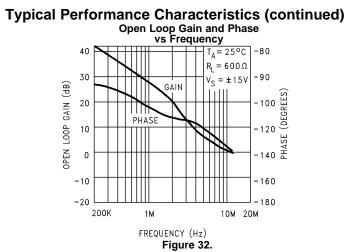


Figure 31.







APPLICATION INFORMATION

DISTORTION MEASUREMENTS

The vanishingly low residual distortion produced by LME49743 is below the capabilities of all commercially available equipment. This makes distortion measurements just slightly more difficult than simply connecting a distortion meter to the amplifier's inputs and outputs. The solution, however, is quite simple: an additional resistor. Adding this resistor extends the resolution of the distortion measurement equipment.

The LME49743's low residual distortion is an input referred internal error. As shown in Figure 33, adding the 10Ω resistor connected between the amplifier's inverting and non-inverting inputs changes the amplifier's noise gain. The result is that the error signal (distortion) is amplified by a factor of 101. Although the amplifier's closed-loop gain is unaltered, the feedback available to correct distortion errors is reduced by 101, which means that measurement resolution increases by 101. To ensure minimum effects on distortion measurements, keep the value of R1 low as shown in Figure 33.

This technique is verified by duplicating the measurements with high closed loop gain and/or making the measurements at high frequencies. Doing so produces distortion components that are within the measurement equipment's capabilities. This datasheet's THD+N and IMD values were generated using the above described circuit connected to an Audio Precision System Two Cascade.

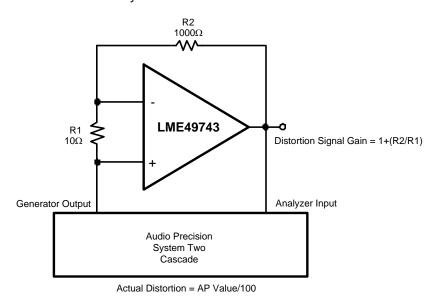


Figure 33. THD+N and IMD Distortion Test Circuit

Application Hints

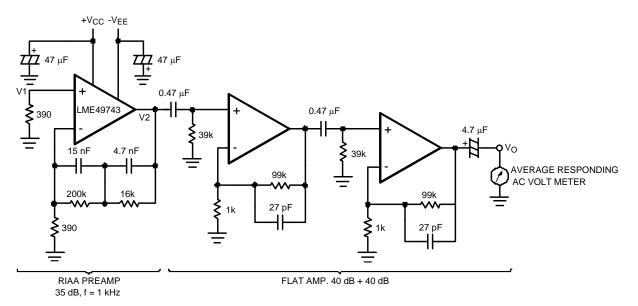
The LME49743 is a high speed op amp with excellent phase margin and stability. Capacitive loads up to 100pF will cause little change in the phase characteristics of the amplifiers and are therefore allowable.

Capacitive loads greater than 100pF must be isolated from the output. The most straightforward way to do this is to put a resistor in series with the output. This resistor will also prevent excess power dissipation if the output is accidentally shorted.

Product Folder Links: LME49743

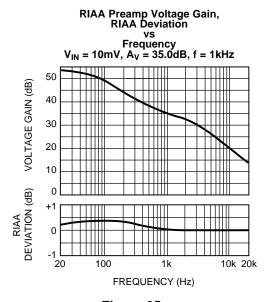


Noise Measurement Circuit



- (1) Complete shielding is required to prevent induced pick up from external sources. Always check with oscilloscope for power line noise.
- (2) Total Gain: 115 dB at f = 1 kHz
- (3) Input Referred Noise Voltage: e_n = V_O/560,000 (V)

Figure 34.





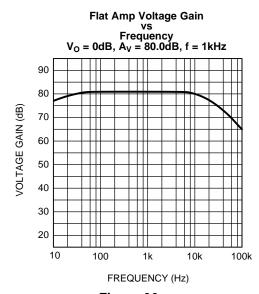
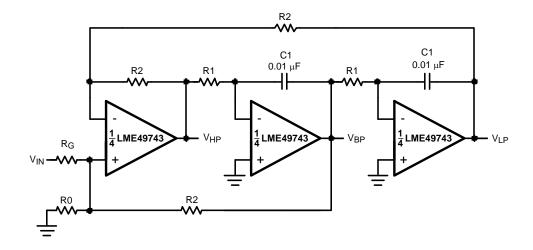


Figure 36.



Typical Applications



$$f_0 = \frac{1}{2\pi C1R1}, Q = \frac{1}{2}\left(1 + \frac{R2}{R0} + \frac{R2}{RG}\right), A_{BP} = QA_{LP} = QA_{LH} = \frac{R2}{RG}$$

Figure 37. State Variable Filter

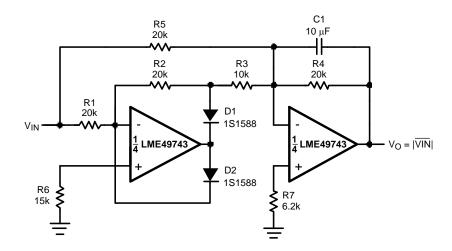


Figure 38. AC-DC Converter



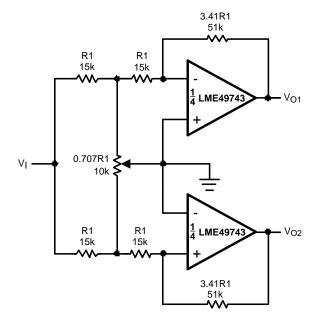


Figure 39. 2 Channel Panning Circuit (Pan Pot)

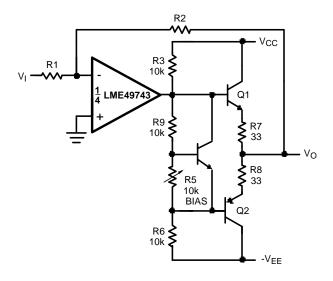
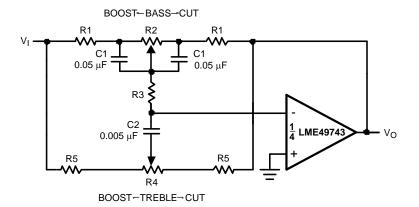


Figure 40. Line Driver





$$f_{L} = \frac{1}{2\pi R2C1}, f_{LB} = \frac{1}{2\pi R1C1}$$

$$f_{H} = \frac{1}{2\pi R5C2}, f_{HB} = \frac{1}{2\pi (R1 + R5 + 2R3)C2}$$

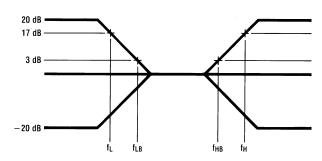
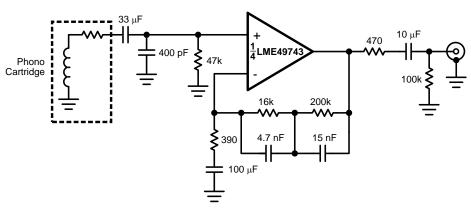


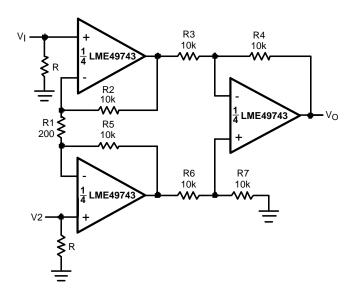
Figure 41. Tone Control



 $A_{\nu}=35~\text{dB}$ $E_{n}=0.33~\mu\text{V}$ S/N = 90 dB f=1~kHz A Weighted, $V_{\text{IN}}=10~\text{mV}$ at f=1~kHz

Figure 42. RIAA Preamp





If R2 = R5, R3 = R6, R4 = R7
$$V0 = \left(1 + \frac{2R2}{R1}\right) \frac{R4}{R3} (V2 - V1)$$
 Illustration is:
$$V0 = 101 (V2 - V1)$$

Figure 43. Balanced Input Mic Amp

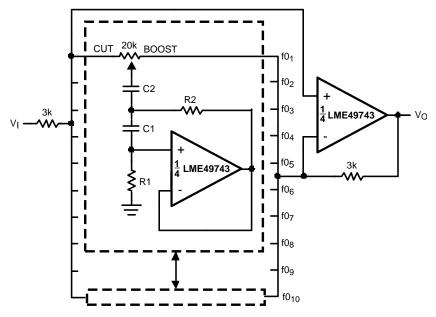


Figure 44. 10 Band Graphic Equalizer

SNAS442B - MARCH 2008-REVISED APRIL 2013



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fo (Hz)	C ₁	C ₂	R ₁	R ₂
32	0.12µF	4.7µF	75kΩ	500Ω
64	0.056µF	3.3µF	68kΩ	510Ω
125	0.033µF	1.5µF	62kΩ	510Ω
250	0.015µF	0.82µF	68kΩ	470Ω
500	8200pF	0.39µF	62kΩ	470Ω
1k	3900pF	0.22µF	68kΩ	470Ω
2k	2000pF	0.1µF	68kΩ	470Ω
4k	1100pF	0.056µF	62kΩ	470Ω
8k	510pF	0.022µF	68kΩ	510Ω
16k	330pF	0.012µF	51kΩ	510Ω

NOTE

At volume of change = $\pm 12 \text{ dB}$

Q = 1.7

Product Folder Links: LME49743



REVISION HISTORY

Rev	Date	Description
1.0	03/26/08	Initial release.
1.01	01/12/09	Fixed a typo.
В	04/04/13	Changed layout of National Data Sheet to TI format.

Submit Documentation Feedback

Product Folder Links: LME49743



PACKAGE OPTION ADDENDUM

10-Sep-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LME49743MT/NOPB	ACTIVE	TSSOP	PW	14	94	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 85	L49743 MT	Samples
LME49743MTX/NOPB	ACTIVE	TSSOP	PW	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 85	L49743 MT	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Sep-2014

In no event shall TI's liabili	ity arising out of such information	exceed the total purchase	price of the TI part(s) at issue	in this document sold by	TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LME49743MTX/NOPB	TSSOP	PW	14	2500	330.0	12.4	6.95	8.3	1.6	8.0	12.0	Q1
LME49743MTX/NOPB	TSSOP	PW	14	2500	330.0	12.4	6.95	8.3	1.6	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	pe Package Drawing		SPQ	Length (mm)	Width (mm)	Height (mm)
LME49743MTX/NOPB	TSSOP	PW	14	2500	367.0	367.0	35.0
LME49743MTX/NOPB	TSSOP	PW	14	2500	349.0	337.0	45.0

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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